

**APJ ABDULKALAM TECHNOLOGICAL UNIVERSITY
08 PALAKKAD CLUSTER**

Q. P. Code : VLS0819312-I

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Name:

Reg. No:.....

SECOND SEMESTER M.TECH. DEGREE EXAMINATION APRIL 2019

Branch: Electronics & Communication Engineering

Specialization: VLSI DESIGN

08EC6312 ANALOG VLSI DESIGN

Time:3 hours

Max.marks: 60

Answer all six questions.

Modules 1 to 6:Part 'a' of each question is compulsory and answer either part 'b' or part 'c' of each question.

Q.no.	Module 1	Marks
1.a	At a room temperature of 300° K, what capacitor size is needed to achieve a 96 dB dynamic range in an analog circuit with maximum signal levels of 1 V rms?	3
Answer b or c		
b	Explain the different types of noise sources in MOS transistor and resistor.	6
c	A large MOS transistor consists of 10 individual transistors connected in parallel . Considering 1/f noise only , what is the equivalent input voltage noise spectral density for the 10 transistors compared to that of a single transistor.	6
Q.no.	Module 2	Marks
2.a	Draw the low frequency model of the source follower amplifier.	3
Answer b or c		
b	Explain the working of current sink and current source with circuit diagram. Also draw its current-voltage characteristics.	6
c	Evaluate the performance of a common source single stage amplifier with required sketches.	6

Q.no.	Module 3	Marks
3.a	Define CMOS differential amplifier.	3

Answer b or c

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|----------|--|----------|
| b | Emphasize the performance of cascode & folded cascode structures with required diagrams. | 6 |
| c | Design a folded cascode opamp for the following requirement: maximum differential swing=2.4V, total power dissipation=6 mW. If all of the transistors have a channel length of 0.5 μ m, what is the overall voltage gain? Can the input common mode level be as low as zero? | 6 |

Q.no.	Module 4	Marks
4.a	List the properties of a current mirror circuit.	3

Answer b or c

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|----------|---|----------|
| b | Design a 2 stage low voltage opamp to meet the specifications given below $V_{DD}=2V$, $V_{icm(max)}=2.5V$, $V_{icm(min)}=1V$, $V_{out(max)}=1.75V$, $V_{out(min)}=0.5V$, $GB=10MHz$, Slew rate=10 V/ μ s phase margin=60 ⁰ for $C_L=10pF$ | 6 |
| c | Discuss in brief about the operations of a micropower op-amp with necessary sketches. | 6 |

Q.no.	Module 5	Marks
5.a	Explain supply independent current with a simple circuit.	4

Answer b or c

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|----------|---|----------|
| b | Emphasize the performance of a switched capacitor integrator circuit with necessary sketches. | 8 |
| c | Discuss the operation of a cmos comparator circuit & a multiplier circuit and compare its performance with required sketches. | 8 |

Q.no.	Module 6	Marks
6.a	Assume that a DAC uses a switched capacitor non inverting amplifier with $C_1=C_2$ and $GB=1 MHz$. Find the conversion time of an 8 bit DAC if V_{REF} is 1V.	4

Answer b or c

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|----------|---|----------|
| b | Discuss in detail about the operation of a PLL with required sketches. Why charge pump & tri-state configurations are used with a PLL design. | 8 |
|----------|---|----------|

c With neat sketches explain the operation of medium speed Analog to Digital Converter. **8**